Data Sheet

Customer：	
Product :	High Power Schottky Diode
Part No.:	MBRF3040CT/MBRF3060CT/MBRF30100CT/MBRF30150CT MBRF30200CT/MBRF30250CT
Issued Date:	11-Jan-11
Edition :	REV.A

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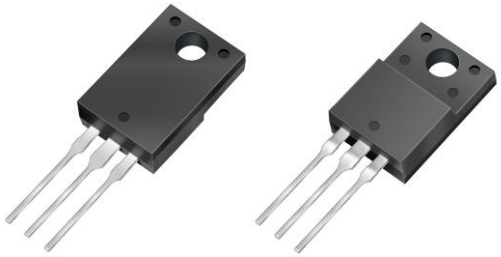
30 Amperes High Power Schottky Barrier Rectifiers
Voltage : 40 to 250Volts

■Features

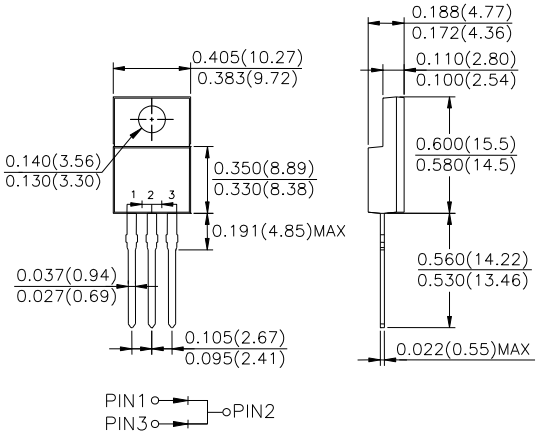
- For use in low voltage, high frequency inverters, free wheeling and polarity protection applications
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- Guardring for overvoltage protection
- Ultra high-speed switching
- Silicon epitaxial planar chip, metal silicon junction
- Lead-free parts meet environmental standards of MIL-STD-19500/228



■Mechanical Data

Epoxy : UL94-V0 rated flame retardant
Case : JEDEC ITO-220AB molded plastic body over passivated chip
Lead : Axial lead, solderable per MIL-STD-202, Method 208 guranteed
Polarity : Color band denotes cathode end
Mounting Position : Any
Weight : Approximated 2.25 gram
Packaging : 50pcs per Tube

■Package Dimensions in inches(millimeters): ITO-220AB



■Maximum Ratings And Electrical Characteristics

Rating at 25℃ ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Parameter	Symbol	MBRF3040CT	MBRF3060CT	MBRF30100CT	MBRF30150CT	MBRF30200CT	MBRF30250CT	Unit
Marking Code		MBRF3040CT	MBRF3060CT	MBRF30100CT	MBRF30150CT	MBRF30200CT	MBRF30250CT	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	40	60	100	150	200	250	V
Maximum RMS Voltage	V_{RMS}	28	42	70	105	140	175	V
Maximum DC Blocking Voltage	V_{DC}	40	60	100	150	200	250	V
Maximum Forward Voltage@15A, T_A=25℃ @15A, T_A=125℃ @30A, T_A=25℃	V_F	0.70 0.57 0.84	0.79 0.70 0.95	0.81 0.71 0.95	0.87 0.77 1.0	0.90 0.80 1.0	0.95 0.85 -	V
Operating Temperature	T_J	-50 ~ +150						℃

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward Rectified Current	See Fig.1	I_O			30	A
Forward Surge Current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I_{FSM}			200	A
Reverse Current	V_R=V_{RRM} , T_A=25℃	I_R			0.1	mA
	V_R=V_{RRM} , T_A=125℃				10	
Thermal Resistance	Junction to ambient	$R_{\Theta JA}$		30		℃/W
Diode Junction Capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		150		pF
Storage Temperature		T_{STG}	-50		+150	℃

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■Rated and Characteristic Curve

Fig.1 - Forward Current Derating Curve

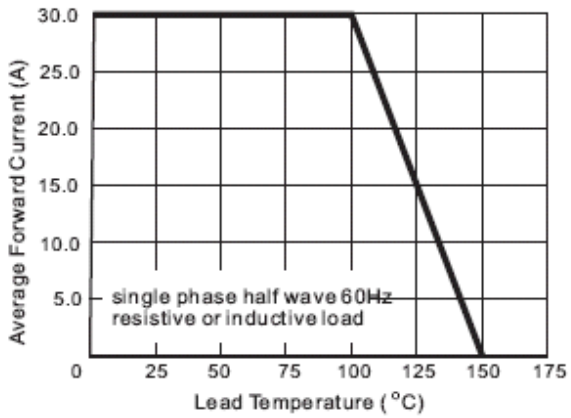


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

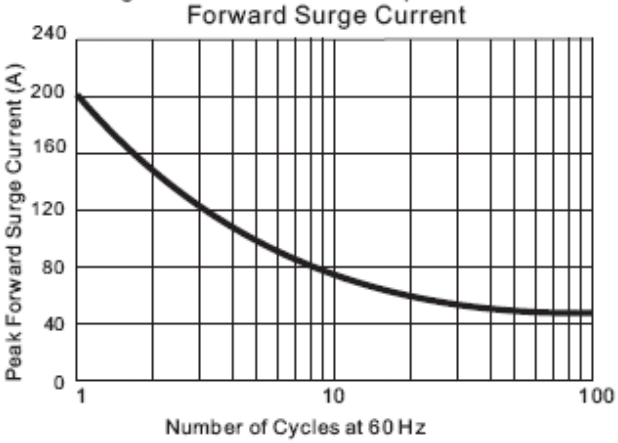


Fig. 3A - Typical Instantaneous Forward Characteristics

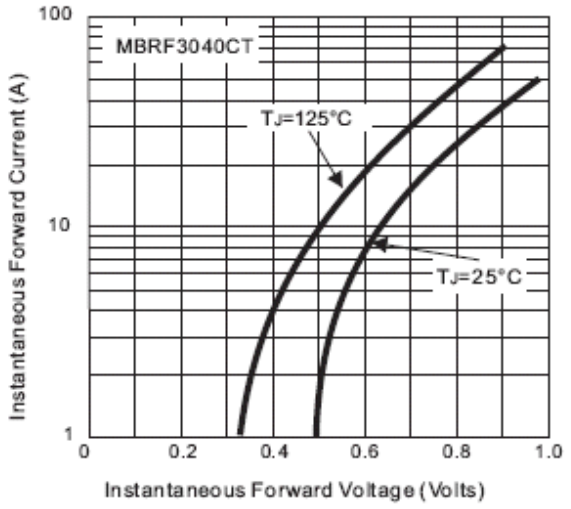


Fig. 3B - Typical Instantaneous Forward Characteristics

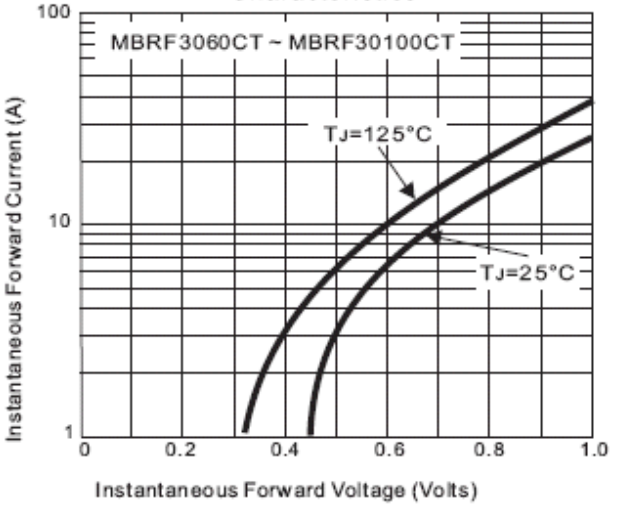


Fig. 3C - Typical Instantaneous Forward Characteristics

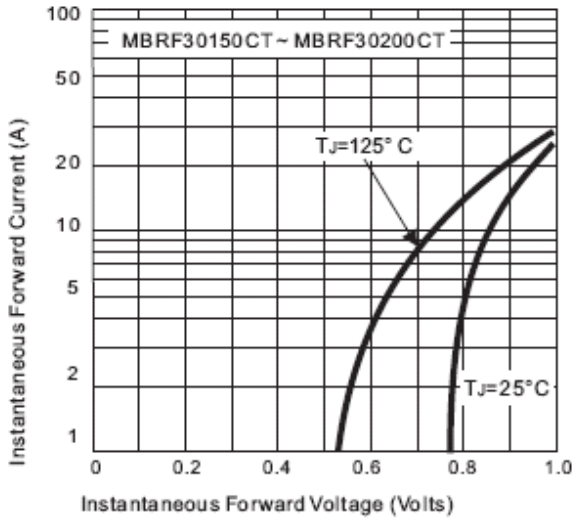
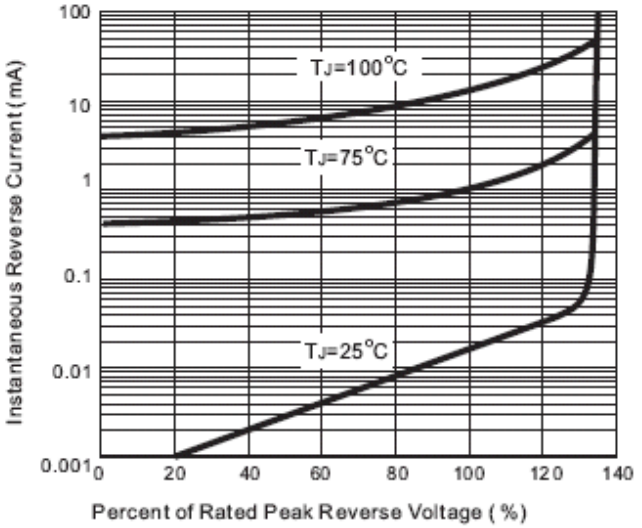


Fig. 4 - Typical Reverse Characteristics



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